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FSB50450A / FSB50450AS / FSB50450AT Motion SPM[®] 5 Series

Features

- UL Certified No. E209204 (UL1557)
- 500 V R_{DS(on)} = 2.4 Ω(Max) FRFET MOSFET 3-Phase Inverter with Gate Drivers and Protection
- · Built-In Bootstrap Diodes Simplify PCB Layout
- Separate Open-Source Pins from Low-Side MOSFETs for Three-Phase Current-Sensing
- Active-HIGH Interface, Works with 3.3 / 5 V Logic, Schmitt-trigger Input
- Optimized for Low Electromagnetic Interference
- HVIC Temperature-Sensing Built-In for Temperature Monitoring
- · HVIC for Gate Driving and Under-Voltage Protection
- Isolation Rating: 1500 V_{rms} / min.
- · Moisture Sensitive Level (MSL) 3
- RoHS Compliant

Applications

 3-Phase Inverter Driver for Small Power AC Motor Drives

Related Source

- RD-FSB50450A Reference Design for Motion SPM 5 Series Ver.2
- AN-9082 Motion SPM5 Series Thermal Performance by Contact Pressure
- AN-9080 User's Guide for Motion SPM 5 Series V2

General Description

The FSB50450A/AS/AT is an advanced Motion SPM® 5 module providing a fully-featured, high-performance inverter output stage for AC Induction, BLDC and PMSM motors. These modules integrate optimized gate drive of the built-in MOSFETs (FRFET® technology) to minimize EMI and losses, while also providing multiple on-module protection features including under-voltage lockouts and thermal monitoring. The built-in HVIC requires only a single supply voltage and translates the incoming logic-level gate inputs to the high-voltage, high-current drive signals required to properly drive the module's internal MOSFETs. Separate open-source MOSFET terminals are available for each phase to support the widest variety of control algorithms.







Package Marking & Ordering Information

Device Marking	Device	ce Package Reel Size Packing Typ		Packing Type	Quantity
FSB50450A	FSB50450A	SPM5P-023	NA	Rail	15
FSB50450AS	FSB50450AS	SPM5Q-023	330mm	Tape-Reel	450
FSB50450AT	FSB50450AT	SPM5N-023	NA	Rail	15

Absolute Maximum Ratings

Inverter Part (each MOSFET unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
V _{DSS}	Drain-Source Voltage of Each MOSFET		500	V
*I _{D 25}	Each MOSFET Drain Current, Continuous	T _C = 25°C	1.5	Α
*I _{D 80}	Each MOSFET Drain Current, Continuous	$T_C = 80^{\circ}C$	1.1	Α
*I _{DP}	Each MOSFET Drain Current, Peak	$T_C = 25^{\circ}C$, PW < 100 μ s	3.9	Α
*I _{DRMS}	Each MOSFET Drain Current, Rms	$T_C = 80$ °C, $F_{PWM} < 20 \text{ kHz}$	0.8	A _{rms}
*P _D	Maximum Power Dissipation	T _C = 25°C, For Each MOSFET	14	W

Control Part (each HVIC unless otherwise specified.)

Symbol	Parameter	Conditions		Unit
V _{CC}	Control Supply Voltage	Applied between V _{CC} and COM	20	V
V _{BS}	High-side Bias Voltage	Applied between V _B and V _S	20	V
V _{IN}	Input Signal Voltage	Applied between V _{IN} and COM	-0.3 ~ V _{CC} + 0.3	V

Bootstrap Diode Part (each bootstrap diode unless otherwise specified.)

Symbol	Parameter	Conditions	Rating	Unit
V_{RRMB}	Maximum Repetitive Reverse Voltage		500	V
* I _{FB}	Forward Current	T _C = 25°C	0.5	Α
* I _{FPB}	Forward Current (Peak)	T _C = 25°C, Under 1ms Pulse Width	1.5	А

Thermal Resistance

Symbol	Parameter	Conditions	Rating	Unit
$R_{ hetaJC}$	Junction to Case Thermal Resistance	Each MOSFET under Inverter Operating Condition (1st Note 1)	8.9	°C/W

Total System

Symbol	Parameter Conditions		Rating	Unit
T _J	Operating Junction Temperature		-40 ~ 150	°C
T _{STG}	Storage Temperature		-40 ~ 125	°C
V _{ISO}	Isolation Voltage	60 Hz, Sinusoidal, 1 Minute, Connect Pins to Heat Sink Plate	1500	V _{rms}

1st Notes

- 1. For the measurement point of case temperature $T_{\mbox{\scriptsize C}},$ please refer to Figure 4.
- 2. Marking " * " is calculation value or design factor.

Pin descriptions

Pin Number	Pin Name	Pin Description
1	СОМ	IC Common Supply Ground
2	V _{B(U)}	Bias Voltage for U-Phase High-Side MOSFET Driving
3	V _{CC(U)}	Bias Voltage for U-Phase IC and Low-Side MOSFET Driving
4	IN _(UH)	Signal Input for U-Phase High-Side
5	IN _(UL)	Signal Input for U-Phase Low-Side
6	N.C	No Connection
7	V _{B(V)}	Bias Voltage for V-Phase High Side MOSFET Driving
8	V _{CC(V)}	Bias Voltage for V-Phase IC and Low Side MOSFET Driving
9	IN _(VH)	Signal Input for V-Phase High-Side
10	IN _(VL)	Signal Input for V-Phase Low-Side
11	V _{TS}	Output for HVIC Temperature Sensing
12	V _{B(W)}	Bias Voltage for W-Phase High-Side MOSFET Driving
13	V _{CC(W)}	Bias Voltage for W-Phase IC and Low-Side MOSFET Driving
14	IN _(WH)	Signal Input for W-Phase High-Side
15	IN _(WL)	Signal Input for W-Phase Low-Side
16	N.C	No Connection
17	Р	Positive DC-Link Input
18	U, V _{S(U)}	Output for U-Phase & Bias Voltage Ground for High-Side MOSFET Driving
19	N _U	Negative DC-Link Input for U-Phase
20	N _V	Negative DC-Link Input for V-Phase
21	V, V _{S(V)}	Output for V-Phase & Bias Voltage Ground for High-Side MOSFET Driving
22	N _W	Negative DC-Link Input for W-Phase
23	W, V _{S(W)}	Output for W Phase & Bias Voltage Ground for High-Side MOSFET Driving

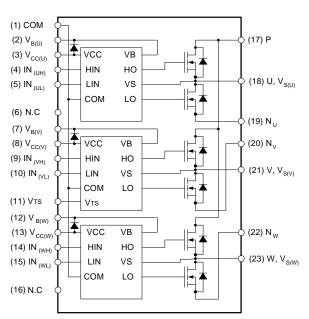


Figure 1. Pin Configuration and Internal Block Diagram (Bottom View)

1st Notes

3. Source terminal of each low-side MOSFET is not connected to supply ground or bias voltage ground inside Motion SPM® 5 product. External connections should be made as indicated in Figure 3.

Electrical Characteristics ($T_J = 25^{\circ}C$, $V_{CC} = V_{BS} = 15 \text{ V}$ unless otherwise specified.)

Inverter Part (each MOSFET unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
BV _{DSS}	Drain - Source Breakdown Voltage	V _{IN} = 0 V, I _D = 1 mA (2nd Note 1)	500	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{IN} = 0 V, V _{DS} = 500 V	-	-	1	mA
R _{DS(on)}	Static Drain - Source Turn-On Resistance	$V_{CC} = V_{BS} = 15 \text{ V}, V_{IN} = 5 \text{ V}, I_D = 1.0 \text{ A}$	-	1.9	2.4	Ω
V _{SD}	Drain - Source Diode Forward Voltage	$V_{CC} = V_{BS} = 15V, V_{IN} = 0 V, I_{D} = -1.0 A$	-	-	1.2	V
t _{ON}		V_{PN} = 300 V, V_{CC} = V_{BS} = 15 V, I_{D} = 1.0 A V_{IN} = 0 V \leftrightarrow 5 V, Inductive Load L = 3 mH High- and Low-Side MOSFET Switching	-	1250	-	ns
t _{OFF}			-	680		ns
t _{rr}	Switching Times		-	200	-	ns
E _{ON}		(2nd Note 2)	-	60	ı	μJ
E _{OFF}			-	10		μJ
RBSOA	Reverse Bias Safe Operating Area	V_{PN} = 400 V, V_{CC} = V_{BS} = 15 V, I_D = I_{DP} , V_{DS} = BV_{DSS} , T_J = 150°C High- and Low-Side MOSFET Switching (2nd Note 3)	Full Square			

Control Part (each HVIC unless otherwise specified.)

Symbol	Parameter		Conditions	Min	Тур	Max	Unit
I _{QCC}	Quiescent V _{CC} Current	V _{CC} = 15 V, V _{IN} = 0 V	Applied between V _{CC} and COM	-	-	200	μА
I _{QBS}	Quiescent V _{BS} Current	V _{BS} = 15 V, V _{IN} = 0 V	Applied between $V_{B(U)}$ - U, $V_{B(V)}$ - V, $V_{B(W)}$ - W	ı	-	100	μА
I _{PCC}	Operating V _{CC} Supply Current	V _{CC} - COM	$V_{\rm CC}$ = 15 V, $f_{\rm PWM}$ = 20 kHz, duty = 50%, Applied to One PWM Signal Input for Low-Side	ı	ı	800	μА
I _{PBS}	Operating V _{BS} Supply Current	$V_{B(U)} - V_{S(U)}, V_{B(V)} - V_{S(V)}, V_{B(W)} - V_{S(W)}$	V _{CC} = V _{BS} = 15 V, f _{PWM} = 20 kHz, Duty = 50%, Applied to One PWM Signal Input for High-Side	-	-	700	μΑ
UV _{CCD}	Low-Side Under-Voltage	V _{CC} Under-Voltage	Protection Detection Level	7.4	8.0	9.4	V
UV _{CCR}	Protection (Figure 8)	V _{CC} Under-Voltage	Protection Reset Level	8.0	8.9	9.8	V
UV _{BSD}	High-Side Under-Voltage	V _{BS} Under-Voltage	Protection Detection Level	7.4	8.0	9.4	V
UV _{BSR}	Protection (Figure 9)	V _{BS} Under-Voltage	Protection Reset Level	8.0	8.9	9.8	V
V _{TS}	HVIC Temperature Sensing Voltage Output $V_{CC} = 15 \text{ V}, T_{HVIC}$: 25°C (2nd Note 4)	600	790	980	mV
V _{IH}	ON Threshold Voltage	Logic HIGH Level	Applied between V. and COM	-	-	2.9	V
V _{IL}	OFF Threshold Voltage	Logic LOW Level	Applied between V _{IN} and COM	0.8	-	-	V

Bootstrap Diode Part (each bootstrap diode unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{FB}	Forward Voltage	$I_F = 0.1 \text{ A}, T_C = 25^{\circ}\text{C} \text{ (2nd Note 5)}$	-	2.5	-	V
t _{rrB}	Reverse Recovery Time	$I_F = 0.1 \text{ A}, T_C = 25^{\circ}\text{C}$	-	80	-	ns

Recommended Operating Condition

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{PN}	Supply Voltage	Applied between P and N	-	300	400	V
V _{CC}	Control Supply Voltage	Applied between V _{CC} and COM	13.5	15.0	16.5	V
V_{BS}	High-Side Bias Voltage	Applied between V_B and V_S	13.5	15.0	16.5	V
V _{IN(ON)}	Input ON Threshold Voltage	Applied between V _{IN} and COM	3.0	-	V _{CC}	V
V _{IN(OFF)}	Input OFF Threshold Voltage	Applied between VIN and COM	0	-	0.6	V
t _{dead}	Blanking Time for Preventing Arm-Short	$V_{CC} = V_{BS} = 13.5 \sim 16.5 \text{ V}, T_{J} \le 150 ^{\circ}\text{C}$	1.0	-	-	μS
f _{PWM}	PWM Switching Frequency	$T_{J} \le 150^{\circ}C$	-	15	-	kHz

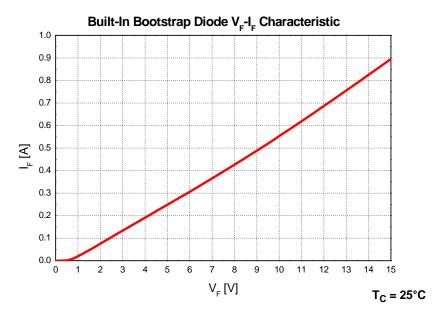


Figure 2. Built-In Bootstrap Diode Characteristics (Typical)

2nd Notes:

- 1. BV_{DSS} is the absolute maximum voltage rating between drain and source terminal of each MOSFET inside Motion SPM[®] 5 product. V_{PN} should be sufficiently less than this value considering the effect of the stray inductance so that V_{PN} should not exceed BV_{DSS} in any case.
- 2. t_{ON} and t_{OFF} include the propagation delay of the internal drive IC. Listed values are measured at the laboratory test condition, and they can be different according to the field applications due to the effect of different printed circuit boards and wirings. Please see Figure 6 for the switching time definition with the switching test circuit of Figure 7.
- 3. The peak current and voltage of each MOSFET during the switching operation should be included in the Safe Operating Area (SOA). Please see Figure 7 for the RBSOA test circuit that is same as the switching test circuit.
- 4. V_{ts} is only for sensing-temperature of module and cannot shutdown MOSFETs automatically.
- 5. Built-in bootstrap diode includes around 15 $\,\Omega$ resistance characteristic. Please refer to Figure 2.

These values depend on PWM control algorithm

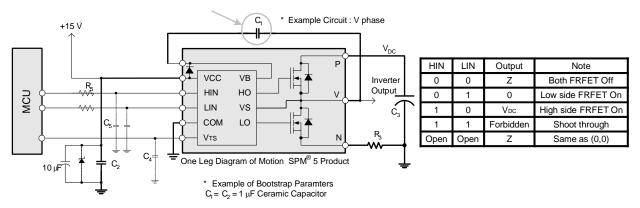


Figure 3. Recommended MCU Interface and Bootstrap Circuit with Parameters

3rd Notes:

- 1. Parameters for bootstrap circuit elements are dependent on PWM algorithm. For 15 kHz of switching frequency, typical example of parameters is shown above.
- 2. RC-coupling (R5 and C5) and C4 at each input of Motion SPM 5 product and MCU (Indicated as Dotted Lines) may be used to prevent improper signal due to surge-noise.
- 3. Bold lines should be short and thick in PCB pattern to have small stray inductance of circuit, which results in the reduction of surge-voltage. Bypass capacitors such as C₁, C₂ and C₃ should have good high-frequency characteristics to absorb high-frequency ripple-current.

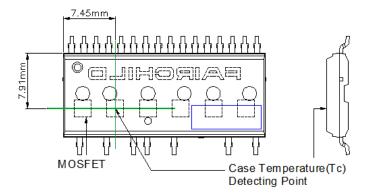


Figure 4. Case Temperature Measurement

3rd Notes:

4. Attach the thermocouple on top of the heat-sink of SPM 5 package (between SPM 5 package and heatsink if applied) to get the correct temperature measurement.

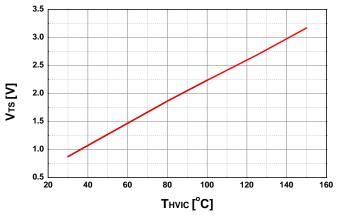


Figure 5. Temperature Profile of V_{TS} (Typical)

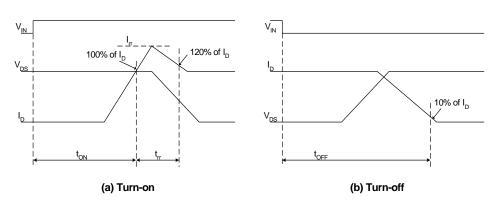


Figure 6. Switching Time Definitions

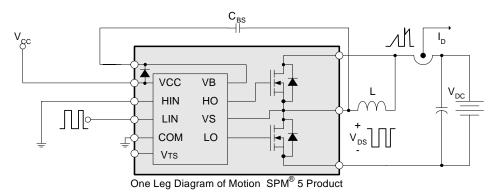


Figure 7. Switching and RBSOA (Single-Pulse) Test Circuit (Low-side)

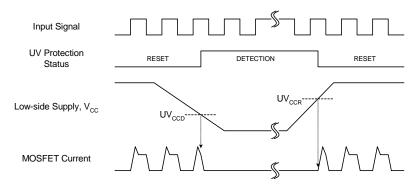


Figure 8. Under-Voltage Protection (Low-Side)

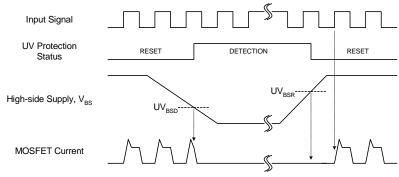


Figure 9. Under-Voltage Protection (High-Side)

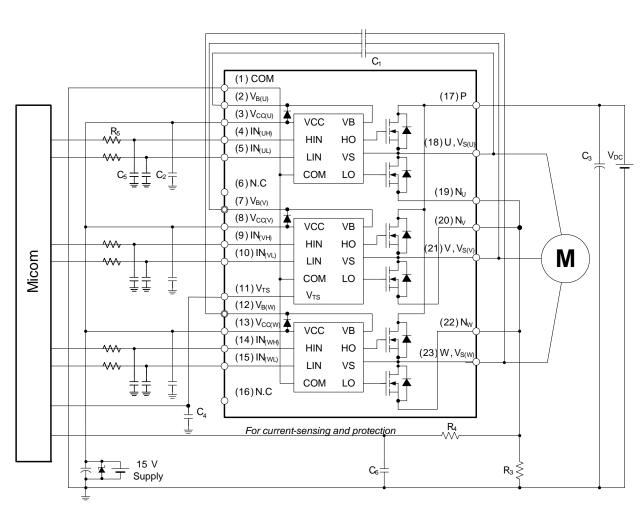
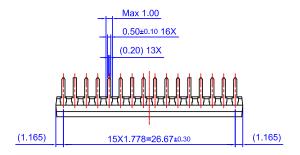


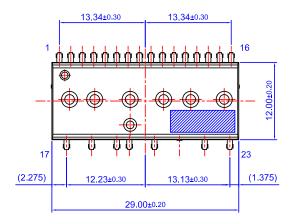
Figure 10. Example of Application Circuit

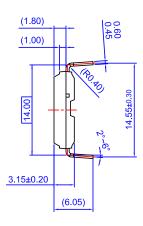
4th Notes

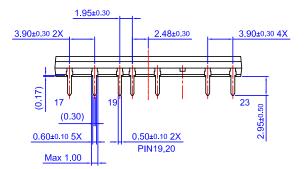
- 1. About pin position, refer to Figure 1.
- 2. RC-coupling (R_5 and C_5 , R_4 and C_6) and C_4 at each input of Motion SPM 8 5 product and MCU are useful to prevent improper input signal caused by surge-noise.
- 3. The voltage-drop across R₃ affects the low-side switching performance and the bootstrap characteristics since it is placed between COM and the source terminal of the low-side MOSFET. For this reason, the voltage-drop across R₃ should be less than 1 V in the steady-state.
- 4. Ground-wires and output terminals, should be thick and short in order to avoid surge-voltage and malfunction of HVIC.
- 5. All the filter capacitors should be connected close to Motion SPM 5 product, and they should have good characteristics for rejecting high-frequency ripple current.

Detailed Package Outline Drawings(FSB50450A)









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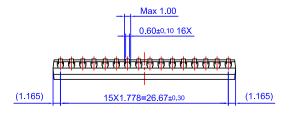


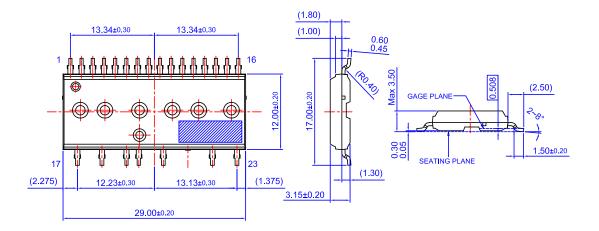
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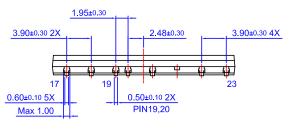
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Detailed Package Outline Drawings(FSB50450AS)



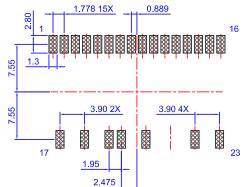




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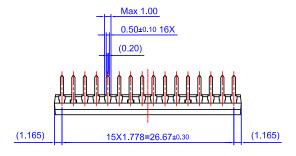
LAND PATTERN RECOMMENDATIONS

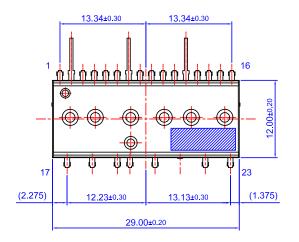
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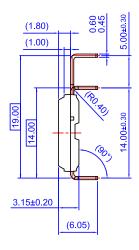
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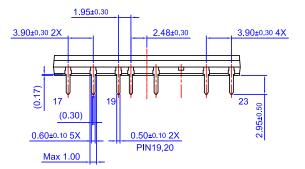
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Detailed Package Outline Drawings(FSB50450AT)









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